Unit: mm

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSVI)

# **TPC8126**

## Lithium Ion Battery Applications Power Management Switch Applications

- Small footprint due to small and thin package
- Low drain-source ON-resistance: RDS (ON) =  $7.5 \text{ m}\Omega$  (typ.)
- Low leakage current:  $IDSS = -10 \mu A (max) (VDS = -30 V)$
- Enhancement mode:  $V_{th}$  = -0.8 to -2.0 V ( $V_{DS}$  = -10 V,  $I_D$  = -0.5mA)

## Absolute Maximum Ratings (Ta = 25°C)

Characteri	stics	Symbol	Rating	Unit	
Drain-source voltage		$V_{DSS}$	-30	V	
Drain-gate voltage (Ro	<sub>SS</sub> = 20 kΩ)	$V_{DGR}$	-30	V	
Gate-source voltage		$V_{GSS}$	-25/+20	V	
Drain current	DC (Note 1)	I <sub>D</sub>	-11	Α	
Diam curient	Pulse (Note 1)	I <sub>DP</sub>	-44		
Drain power dissipation	n (t = 10 s) (Note 2a)	$P_{D}$	1.9	W	
Drain power dissipation	n (t = 10 s) (Note 2b)	$P_{D}$	1.0	W	
Single pulse avalanch	e energy (Note 3)	E <sub>AS</sub>	79	mJ	
Avalanche current	(Note 1)	I <sub>AR</sub>	-11	Α	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	

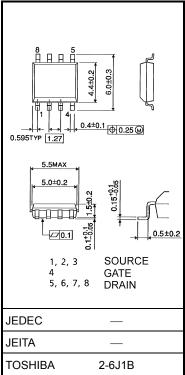
Note 1, Note 2, Note 3: See the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating

temperature/current/voltage, etc.) are within the absolute maximum

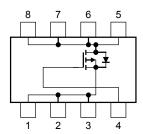
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.080 g (typ.)

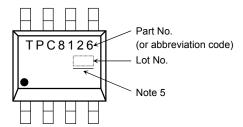
### **Circuit Configuration**



#### **Thermal Characteristics**

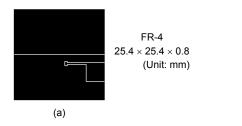
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R <sub>th (ch-a)</sub>	65.8	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R <sub>th (ch-a)</sub>	125	°C/W

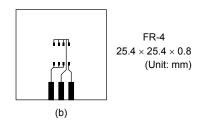
## Marking (Note 4)



Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a)Device mounted on a glass-epoxy board (b) (b)Device mounted on a glass-epoxy board (b)

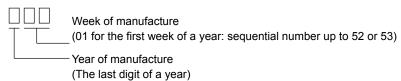




Note 3:  $V_{DD} = -24~V,~T_{Ch} = 25~^{\circ}C$  (initial),  $L = 500~\mu H,~R_G = 25~\Omega,~I_{AR} = -11~A$ 

Note 4: • on lower left of the marking indicates Pin 1.

Weekly code: (Three digits)



Note 5: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

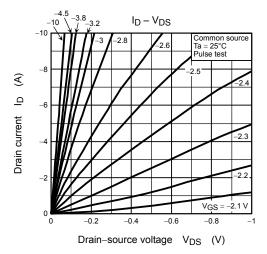
## Electrical Characteristics (Ta = 25°C)

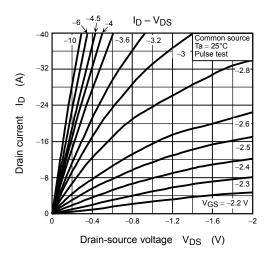
Char	acteristics	Symbol	Test Condition	Min Typ. Max		Unit	
Gate leakage curre	ent	I <sub>GSS</sub>	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±100	nA
Drain cut-OFF curr	ent	I <sub>DSS</sub>	$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}$	_		-10	μА
Drain aguras brasil	rdovin volto ao	V (BR) DSS	$I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$ -30		_	_	V
Drain-source break	down voltage	V (BR) DSX	$I_D = -10 \text{ mA}, V_{GS} = 10 \text{ V}$ (Note 6)	-21	- ±100 10 -30	V	
Gate threshold volt	age	V <sub>th</sub>	$V_{DS} = -10 \text{ V}, I_D = -0.5 \text{ mA}$	-0.8 — -2.0		V	
Drain course ON r	naiatanaa	Dec (c)	$V_{GS} = -4.5 \text{ V}, I_D = -5.5 \text{ A}$	_	10.5	14	mΩ
Diain-source ON-II	N-resistance ce er capacitance	R <sub>DS</sub> (ON)	$V_{GS} = -10 \text{ V}, I_D = -5.5 \text{ A}$	_	7.5	10	
Input capacitance	Input capacitance		V <sub>DS</sub> = -10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	2400	_	pF
Reverse transfer capacitance		C <sub>rss</sub>		_	400	_	
Output capacitance		Coss		_	460	_	
	Rise time	t <sub>r</sub>	$V_{CS} = 0 \text{ V}        $	_	8	_	
Switching time	Turn-ON time	ton	VGS _10 V	— — ±10 — — — 10 — — — — 10 — — — — — — — — — — — — — — — — — — —	_		
Switching time	Fall time	t <sub>f</sub>	ш.	_	65	_	ns
	Turn-OFF time	t <sub>off</sub>	$V_{DD} \approx -15 \text{ V}$ Duty $\leq$ 1%, $t_W = 10 \mu\text{s}$	_	200	_	
Total gate charge (gate-source plus gate-drain)		Qg	V <sub>DD</sub> ≈ -24 V, V <sub>GS</sub> = -10 V,		56	_	nC
Gate-source charge 1		Q <sub>gs1</sub>	$I_D = -11 \text{ A}$	_	5.6	_	
Gate-drain ("miller") charge		Q <sub>gd</sub>			15	_	

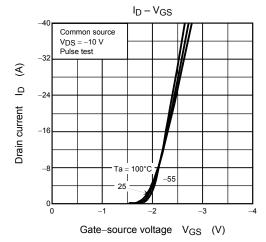
## Source-Drain Ratings and Characteristics (Ta = 25°C)

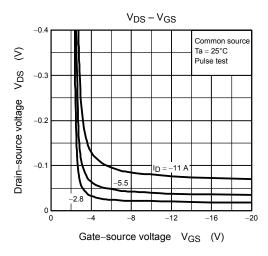
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Drain reverse current	Pulse	(Note 1)	I <sub>DRP</sub>	_	_	_	-44	Α
Forward voltage (diode)		V <sub>DSF</sub>	I <sub>DR</sub> = -11 A, V <sub>GS</sub> = 0 V	_	_	1.2	V	

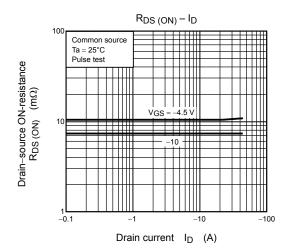
Note 6: VDSX mode (the application of a plus voltage between gate and source) may cause decrease in maximum rating of drain-source voltage.



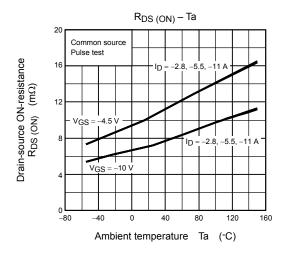


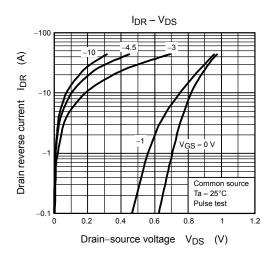


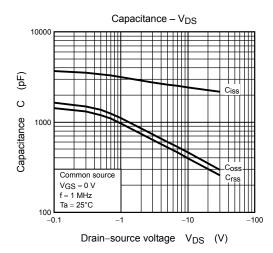


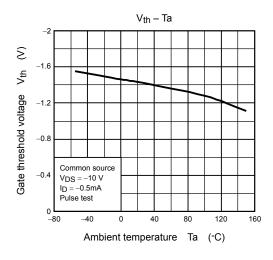


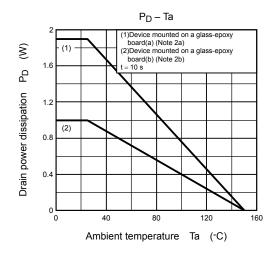
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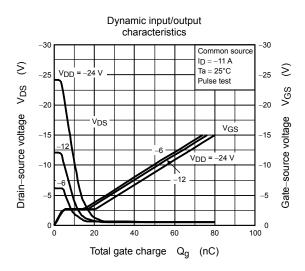




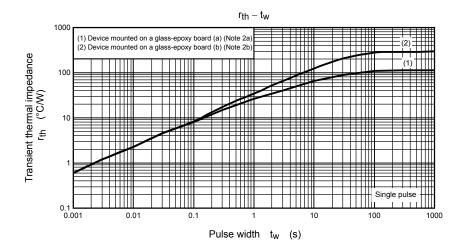


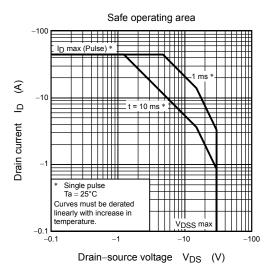






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